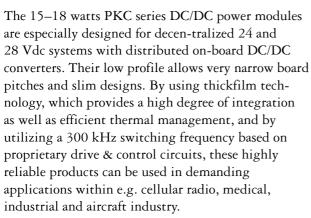
15–18 W DC/DC Power Modules 24 V Input Series

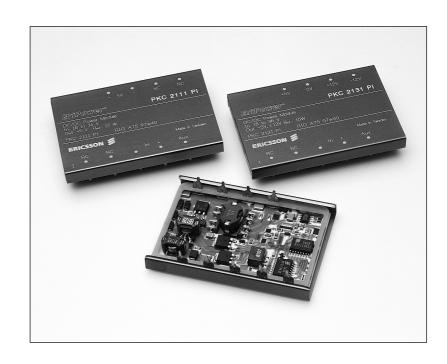
- Regulated single, dual and triple outputs
- Low profile 10.7 mm (0.42 in.), allows 0.8" board pitch – 0.6 in. if recessed in the printed board
- Proven MTBF >2,000,000 hours at +75 °C case temperature and a rugged mechanical construction
- Efficiency 85% typ, at full load. No extra heatsink up to +85°C ambient. Max.+115°C case
- Low EMI in conformance with class A in EN 55022 and FCC part 15I







By using magnetic integration of the output voltages in the feedback loop, all outputs are kept within a $\pm 3\%$ total tolerance band. Input to output isolation is



500 Vdc and mechanical ruggedness – specified in conformance with IEC 68-2 – is close to requirements for discrete components. Extreme temperature conditions can be met since the PKC power modules can operate with full output power in ambient temperatures from –45 to +85°C, or up to +115°C case temperature also making the products ideal for applications within not temperature controlled environments.

The PKC series are manufactured using highly automated manufacturing lines with a world-class quality commitment and a five-year warranty. Ericsson Microelectronics AB has been an ISO 9001 certified supplier since 1991. For a complete product program please reference the back cover.



General

Absolute Maximum Ratings

Charact	eristics	min	max	Unit
T _C	Case temperature ¹⁾	-45	+115	°C
T _S	Storage temperature	-55	+125	°C
Vi	Input voltage	-0.5	36	Vdc
V _{ISO}	Input to output isolation	500		Vdc
W _{tr}	Transient input energy ²⁾		0.6	Ws
V _{RC}	Remote control voltage pin 1	0	5	Vdc

Stress in excess of Absolute Maximum
Ratings may cause permanent damage. Absolute
Maximum Ratings, sometimes referred to as no
destruction limits, are normally tested with one
parameter at a time exceeding the limits of
Output data or Electrical Characteristics. If
exposed to stress above these limits, function and
performance may degrade in an unspecified
manner.

Input T_C < T_{Cmax} unless otherwise specified

Charac	teristics	Conditions	min	typ	max	Unit
Vi	Input voltage range ³⁾		18		36	V
Vioff	Turn-off input voltage	(See Operating Information)	13		17	V
V _{Ion}	Turn-on input voltage	(See Operating Information)	14 18		V	
r _{Irush}	Equivalent inrush current resistance			600		mΩ
Cı	Input capacitance			1.4		μF
P _{li}	Input idling power	I _O = 0, T _C = 0+95 °C		2		W
P _{RC}	Input stand-by power	$V_1 = 26V$, $I_O = 0$, $T_C = 0+95$ °C, RC connected to pin 3		0.6		W

Safety

The PKC 2000 I DC/DC power modules are designed in accordance with EN 60 950. Safety of information technology equipment including electrical business equipment. and certified by SEMKO.

The isolation is an operational insulation in accordance with EN 60950. The PKC power modules are recognized by UL and meet the applicable requirements in UL 1950 Safety of information technology equipment, the applicable canadian safety requirements and UL 1012 standard for power supplies. The DC/DC power module shall be installed in an end-use equipment.

The isolation voltage between input and output and between case and input/output is 500 Vdc and the capacitor between the input and output has a value of 10 nF. The leakage current is less than 1uA @ 26 Vdc.

The case is partly designed in non-coductive plastic. Flammability ratings meets UL 94V-0.

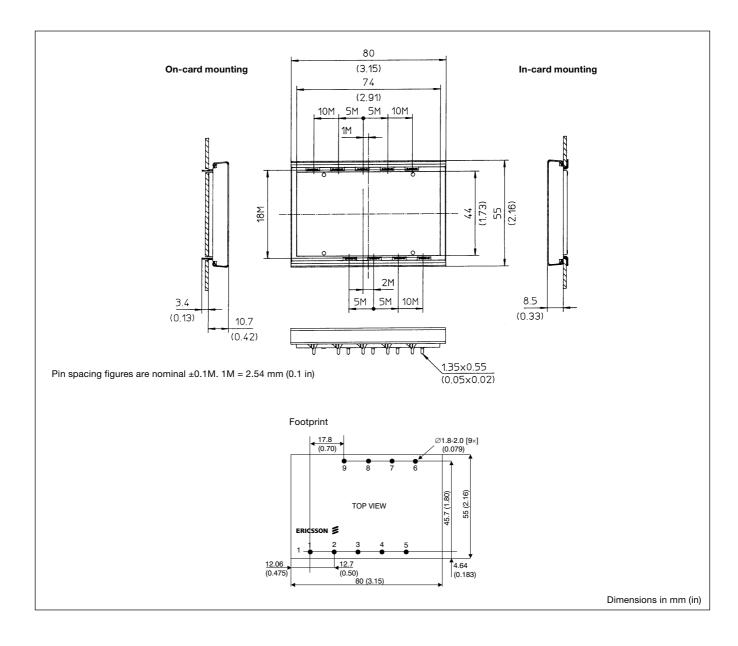
Environmental Characteristics

Characteristics	Test procedure & co	nditions	
Vibration (Sinusoidal)	IEC 68-2-6 F _c	Frequency Amplitude Acceleration Number of cycles	10500 Hz 0.75 mm 10 g 10 in each axis
Shock (Half sinus)	IEC 68-2-27 E _a	Peak acceleration Shock duration	200 g 3 ms
Bump (Half sinus)	IEC 68-2-29 E _b	Peak acceleration Bump duration Number of bumps	40 g 6 ms 1000 in 6 directions
Temperature change	IEC 68-2-14 N _a	Temperature Number of cycles	-40°C+125°C 10
Damp heat	IEC 68-2-3 C _a	Temperature Duration	40°C 56 days
Accelerated damp heat	IEC 68-2-3 C _a with bias	Temperature Humidity Duration	85°C 85% RH 500 hours
Solder resistability	IEC 68-2-20 T _b 1A	Temperature,solder Duration	260°C 1013 s

Notes:

- $^{1)}$ Corresponding ambient temp. range (TA) at full output power is -45 to $+85\,^{\circ}\text{C}.$
- ²⁾ $P<1~kW,~t_r/t_d=10/1000~ms,~I_I<8~A.$ Transient supressor threshold voltage is 39 V typ.
- $^{3)}$ The converters will operate down to $V_{\rm I}{\le}17$ V, when $V_{\rm I}$ decreases, but will turn on at $V_{\rm I}{\le}18$ V, when $V_{\rm I}$ increases (see also Operating information).

Mechanical Data



Connections

Pin	Designation	Function
1	RC	Remote Control to turn-on and turn-off the output. It is also used to adjust the turn-off input voltage threshold (see V _{loff} p.15)
2	NC	The pin is Not Connected
3	-In	Negative Input terminal
4	+In	Positive Input terminal
5	Aux	Auxiliary terminal (see V _{loff} p. 15)
6	Out	Negative Output terminal. Output 2 in dual and Output 3 in triple output models
7	Out	Positive Output terminal. Output 2 in triple output models. Additional return in dual versions
8	Rtn	Return terminal for all outputs
9	Out	Positive Output terminal. Output 1 in all models

Weight

50 gr (1.76 oz).

Case

Blue anodized aluminum case with a plastic bottom cover and with tin plated brass pins.

Thermal Data

Two-parameter model

Power dissipation is generated in the components mounted on the ceramic substrate. The thermal properties of the PKC power module is determined by thermal conduction in the connected pins and thermal convection from the substrate via the case.

The two-parameter model characterize the thermal properties of the PKC power module and the equation below can be used for thermal design purposes if detailed information is needed. The values are given for a module mounted on a printed board assembly (PBA).

Note that the thermal resistance between the substrate and the air, $R_{\text{th sub-A}}$ is strongly dependent on the air velocity.

$$\begin{split} T_{sub} &= P_d \times R_{th \; sub\text{-}P} \times R_{th \; sub\text{-}A} / (R_{th \; sub\text{-}P} + R_{th \; sub\text{-}A}) + (T_P - T_A) \\ &\times R_{th \; sub\text{-}A} / (R_{th \; sub\text{-}P} + R_{th \; sub\text{-}A}) + T_A \end{split}$$

Where:

 $\begin{array}{ll} P_{\rm d} & : \mbox{dissipated power, calculated as } P_{\rm O} \times (1/\eta\text{-}1). \\ T_{sub} & : \mbox{max average substrate temperature,} \approx T_{Cmax}. \end{array}$

T_A : ambient air temperature at the lower side of the power

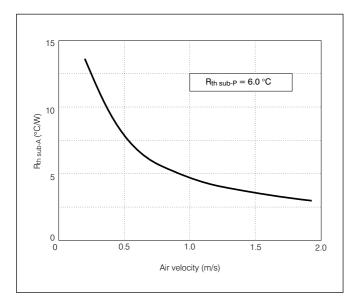
module.

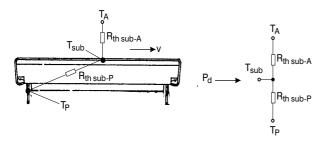
T_P : average pin temperature or solder joint temperature.

 $R_{th\;sub\text{-}P}$: thermal resistance from T_{sub} to the pins. $R_{th\;sub\text{-}A}$: thermal resistance from T_{sub} to T_A .

v : velocity of ambient air.

Air velocity in free convection is 0.2–0.3 m/s (40-60 lfm).

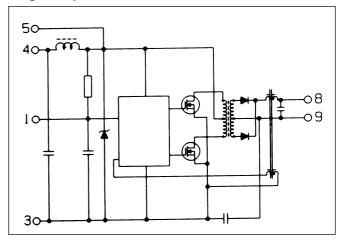




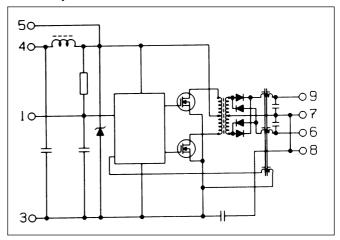
Electrical Data

Fundamental circuit diagrams

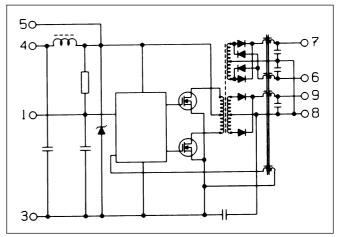
Single output



Dual output



Triple output



PKC 2111 PI

 $T_C = 0...+95\,^{\circ}C$, $V_I = 18...36\,V$ unless otherwise specified.

Output

					Output 1		
Charac	teristics	Conditions		min	typ	max	- Unit
V _{Oi}	Output voltage initial setting and accuracy	T _C = +25 °C, I _O = 37	A, V _I = 26 V	5.02	5.06	5.11	V
Vo	Output voltage tolerance band	$I_O=0.1$ 1.0 × I_{OT} and long term drift		4.90		5.25	V
	Idling circuit voltage	I _O = 0 A				5.25	V
	Line regulation	I _O =I _O max				90	mV
	Load regulation	I _O =0.1 1.0 × I _O	max, V _I = 26 V			150	mV
t _{tr}	Load transient recovery time	I _O =0.1 1.0 × I _O n load step = 2.4 A	nax, V _I = 26 V		100		μs
V _{tr}	Load transient voltage	$\frac{\text{di}}{\text{dt}} < 1\text{A}/\mu\text{s}$			+250		mV
Vtr	Load transient voltage	dt '			-250		mV
	Short term drift	t = 010 minutes	t = 010 minutes		-15		mV
T _{coeff}	Temperature coefficient	I _O =I _O max, T _C < T _C m	ax		-0.5		mV/°C
t _r	Ramp-up time	I _O =	0.1 0.9 × V _O		20		ms
ts	Start-up time	0.1 $1.0 \times I_{Omax}$, $V_I = 26 \text{ V}$	From V_I connection to $V_O = 0.9 \times V_{Oi}$		30		ms
lo	Output current			0		3.0	А
Pomax	Max output power	*		15			W
I _{lim}	Current limiting threshold	T _C < T _C max		3.1			А
I _{sc}	Short curcuit current	V _O = 0.2 0.5 V, T _A	_A =25°C Hick-up		<0.5		А
			20 Hz 5 MHz			100	mV _{p-p}
V _O ac	Output ripple & noice	I _O =I _O max	DC 50 MHz			120	mV _{p-p}
			1 MHz bandwidth			35	mVrms
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wa (SVR = 20 log (1 V _E	ve, 1 V _P -p, V _I = 26 V ₂ -p/V _{O p} -p))	50			dB

^{*} See also Power derating p. 12

Characteristics		Conditions	min	typ	typ max	
η	Efficiency	$I_O = I_{Omax}$, $V_I = 26 V$	80.5	81.5		%
P _d	Power dissipation	I _O =I _O max		3.4		W

PKC 2113 PI

 T_C = 0...+95°C, V_I = 18...36V unless otherwise specified.

Output

Ob and at		O - m diski - m -			Output 1		1114
Charact	eristics	Conditions		min	typ	max	- Unit
V _{Oi}	Output voltage initial setting and accuracy	$T_C = +25$ °C, $I_O = 1.8$	5A, V _I = 26 V	11.94	12.00	12.06	V
Vo	Output voltage tolerance band	$I_O=0.1$ 1.0 × I_{OR} and long term drift		11.80		12.35	V
	Idling circuit voltage	I _O = 0 A				12.40	V
	Line regulation	I _O =I _O max	O=I _O max			168	mV
	Load regulation	I _O =0.1 1.0 × I _O r	max, V _I = 26 V			360	mV
t _{tr}	Load transient recovery time	l ₀ =0.1 1.0 × l ₀ m load step = 1.2 A	nax, V _I = 26 V		200		μЅ
V _{tr}	Load transient voltage	$\frac{di}{dt} < 1A/\mu s$			+600		mV
Vtr	Load transient voltage	dt			-600		mV
	Short term drift	t = 010 minutes	t = 010 minutes		-45		mV
T _{coeff}	Temperature coefficient	$I_O = I_O \max$, $T_C < T_C \min$	ax		-1.5		mV/°C
t _r	Ramp-up time	I _O =	0.1 0.9 × V _O		20		ms
ts	Start-up time	0.1 $1.0 \times I_{O}$ max, $V_{I} = 26 \text{ V}$	From V_i connection to $V_O = 0.9 \times V_{Oi}$		30		ms
lo	Output current			0		1.5	А
Pomax	Max output power	*		18			W
l _{lim}	Current limiting threshold	T _C < T _C max		1.6			А
I _{sc}	Short curcuit current	V _O = 0.2 0.5 V, T _A	V _O = 0.2 0.5 V, T _A = 25 °C Hick-up		<0.5		А
			20 Hz 5 MHz			80	mV _{p-p}
V _O ac	Output ripple & noice	I _O =I _O max	DC 50 MHz			100	mV _{p-p}
			1 MHz bandwidth			25	mVrms
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wa (SVR = 20 log (1 Vp	ve, 1 V _{p-p} , V _I = 26 V - _p /V _{Op-p}))	43			dB

^{*} See also Power derating p. 12

Characte	eristics	Conditions	min	typ	max	Unit
η	Efficiency	I _O =I _O max, V _I = 26 V	84	85		%
P _d	Power dissipation	I _O =I _O max		3.2		W

PKC 2121 PI

 $T_C = 0...+95^{\circ}C$, $V_I = 18...36V$ unless otherwise specified. $I_{O1nom} = 0.75A$, $I_{O2nom} = 0.75A$

Output

Ob	L:1-41	0			Output 1			Output 2	2	11
Charact	teristics	Conditions		min	typ	max	min	typ	max	Unit
V _{Oi}	Output voltage initial setting and accuracy	$T_C = +25 ^{\circ}C, I_O = I_O$	nom, V _I = 26 V	11.91	12.00	12.09	-11.84	-12.00	-12.16	V
Vo	Output voltage tolerance band	I _{O1} =0.1 1.0×I _{O1} and long term drift		11.75		12.35	11.64		12.36	V
	Idling circuit voltage	I _O = 0 A				12.40		15	20	V
	Line regulation	I _O =I _O nom				120			144	mV
	Load regulation	$I_{O1}=0.1 1.0 \times I_{O}$ $V_{I}=26 \text{ V}$	nom, I _{O2} =I _O nom,			360				mV
t _{tr}	Load transient recovery time	load step = 0.6 A s	ope 0.1 1.0 × I _{O nom} , V _I = 26 V bad step = 0.6 A symmetrical load,		200			200		μS
V	Load transient valtage	$I_{01} = I_{02}$			+600			+600		mV
V _{tr}	Load transient voltage	di dt <1A/μs			-600			-600		mV
	Short term drift	t = 010 minutes	t = 010 minutes		-30			-30		mV
T _{coeff}	Temperature coefficient	I _O =I _O nom, T _C < T _C m	ax		-1.0			-1.0		mV/°C
t _r	Ramp-up time	I _O =	0.1 0.9 × V _O		20			20		ms
ts	Start-up time	$0.1 1.0 \times I_{O}$ nom, $V_{I} = 26 \text{ V}$	From V_i connection to $V_O = 0.9 \times V_{Oi}$		30			30		ms
lo	Output current			0		1.2	0		1.2	Α
Pomax	Max total output power	*				mir	18			W
I _{lim}	Current limiting threshold	T _C < T _C max				min 1.02	× P _O max**	·		
I _{sc}	Short curcuit current	V _O = 0.2 0.5 V, T _A	₄ =25°C Hick-up		<0.5			<0.5		Α
			20 Hz 5 MHz			90			90	mV _{P-P}
V _O ac	Output ripple & noice	I _O =I _O nom	DC 50 MHz			110			110	mV _{P-p}
			1 MHz bandwidth			25			30	mVrms
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wa (SVR = 20 log (1 Vp	ve, 1 V _P -p, V _I = 26 V -p/V _{OP} -p))	43			43			dB

^{*} See also Power derating p. 12

Characteristics		Conditions	min	typ	max	Unit
η	Efficiency	I _O =I _{Onom} , V _I = 26 V	84	86		%
P _d	Power dissipation	I _O =I _O nom		2.9		W

^{**} I_{lim} on each output is set by the total load

PKC 2126 PI

 $T_C = 0...+95$ °C, $V_I = 18...36$ V unless otherwise specified. $I_{O1nom} = 0.6$ A, $I_{O2nom} = 0.6$ A

Output

Chavast	ta viakia a	Conditions			Output 1			Output 2	2	Unit
Charact	eristics	Conditions		min	typ	max	min	typ	max	Unit
V _{Oi}	Output voltage initial setting and accuracy	$T_C = +25^{\circ}C, I_O = I_O$	nom, V _I = 26 V	14.89	15.0	15.11	-14.82	-15.0	-15.18	V
V _O	Output voltage tolerance band	I _{O1} =0.1 1.0×I _{O1} and long term drift	on = 0.1 1.0×I _O nom, I _{O2} =I _O nom and long term drift			15.40	14.55		15.45	V
	Idling voltage	I _O = 0 A				15.45		18	23	V
	Line regulation	I _O =I _O nom	l _O nom			240			270	mV
	Load regulation	$I_{O1}=0.1$ $1.0 \times I_{O}$ $V_{I}=26 \text{ V}$	nom, I _{O2} = I _O nom,			450				mV
t _{tr}	Load transient recovery time	load step = 0.48 A	$_{O}$ =0.1 1.0 × I_{O} nom, V_{I} = 26 V oad step = 0.48 A symmetrical load,		250			250		μs
V _{tr}	Load transient voltage	$I_{01} = I_{02}$			+750			+750		mV
Vtr	Load transient voltage	di/dt <1A/μs			-750			-750		mV
	Short term drift	t = 010 minutes	t = 010 minutes		-30			-30		mV
T _{coeff}	Temperature coefficient	I _O =I _O nom, T _C < T _C m	ax		-1.0			-1.0		mV/°C
t _r	Ramp-up time	I _O =	0.1 0.9 × V _O		20			20		ms
ts	Start-up time	0.1 $1.0 \times I_{O} \text{ nom},$ $V_{I} = 26 \text{ V}$	From V_l connection to $V_O = 0.9 \times V_{Oi}$		30			30		ms
lo	Output current			0		1.0	0		1.0	Α
Pomax	Max total output power	*				mir	n 18			W
I _{lim}	Current limiting threshold	T _C < T _C max				min 1.02	× P _O max**			
I _{sc}	Short curcuit current	V _O = 0.2 0.5 V, T _A	=25°C Hick-up		<0.5			<0.5		Α
			20 Hz 5 MHz			90			90	mV _{p-p}
Voac	Output ripple & noice	I _O =I _O nom	DC 50 MHz			110			110	mVp-p
			1 MHz bandwidth			25			30	mV _{rms}
SVR	Supply voltage rejection (ac)	f = 100 Hz sine way (SVR = 20 log (1 V _p	ve, 1 V _{P-P} , V _I = 26 V -p/V _{OP-p}))	40			40			dB

^{*} See also Power derating p. 12

Characteristics		Conditions	min	typ	max	Unit
η	Efficiency	I _O =I _O nom, V _I = 26 V	84	86.5		%
P _d	Power dissipation	I _O =I _O nom		2.8		W

^{**} I_{lim} on each output is set by the total load

PKC 2131 PI

 $T_C = 0...+95$ °C, $V_I = 18...36$ V unless otherwise specified. $I_{O1nom} = 2.0$ A, $I_{O2, 3nom} = 0.2$ A

Output

Chara		Conditions			Output 1		Output 2			Output 3			Unit
Cnara	cteristics	Conditions		min	typ	max	min	typ	max	min	typ	max	Unit
V _{Oi}	Output voltage initial setting and accuracy	$T_C = +25 ^{\circ}C, I_O = I_{O}$	nom, V _I = 26 V	5.02	5.06	5.11	11.94	12.10	12.26	-11.94	-12.10	-12.26	V
Vo	Output voltage tolerance band	$I_O=0.1$ 1.0 × I_{OR} and long term drift		4.90		5.25	11.64		12.36	11.64		12.36	٧
	Idling voltage	I _O = 0 A				5.25		15.00	16.80		15.00	16.80	V
	Line regulation	I _O =I _O nom				81			288			288	mV
	Load regulation	$I_{O1} = 0.1 1.0 \times I_{O}$ $V_{I} = 26 \text{ V}$	nom, I _{O2, 3} = I _O nom,			162							mV
t _{tr}	Load transient recovery time	I _O =0.1 1.0 × I _O nom, V _I = 26 V load step = 80% of I _O nom			100			200			200		μS
V_{tr}	Load transient voltage	$\frac{di}{dt} < 1A/\mu s$			+250			+600			+600		mV
Vtr	Load transient voltage	at			-250			-600			-600		mV
	Short term drift	t = 010 minutes			-15			-36			-36		mV
T _{coeff}	Temperature coefficient	I _O =I _O nom, T _C <t<sub>C m</t<sub>	ax		-0.5			-1.2			-1.2		mV/°C
t _r	Ramp-up time	I _O =	$0.1\dots\ 0.9\times V_O$		20			20			20		ms
ts	Start-up time	$0.1 1.0 \times I_{O} \text{ nom,}$ $V_{I} = 26 \text{ V}$	From V_1 connection to $V_0 = 0.9 \times V_{Oi}$		30			30			30		ms
lo	Output current			0		3.0	0		0.6	0		0.6	Α
Pomax	Max total output power	*					min 15						W
l _{lim}	Current limiting threshold	T _C < T _C max					min 1.02 × P _O max**						
I _{sc}	Short curcuit current	V _O = 0.2 0.5 V, T _A	4=25°C Hick-up		<0.5			<0.5			<0.5		Α
			20 Hz 5 MHz			100			110			100	mV _{p-p}
V _O ac	Output ripple & noice	I _O =I _O nom	DC 50 MHz			130			150			150	mV _{p-p}
			1 MHz bandwidth			40			40			40	mV _{rms}
SVR	Supply voltage rejection (ac)	f = 100 Hz sine way (SVR = 20 log (1 V _p		50			43			43			dB

 $^{^{\}star}$ See also Power derating p. 13. Max output power on output 2 and 3 jointly is min 10 W

Characte	eristics	Conditions	min	typ	max	Unit
η	Efficiency	I _O =I _O nom, V _I = 26 V	79.5	81		%
P _d	Power dissipation	I _O =I _O nom		3.5		W

 $^{^{**}\,} I_{\text{lim}}$ on each output is set by the total load

PKC 2132 PI

 $T_C = 0...+95$ °C, $V_I = 18...36V$ unless otherwise specified. $I_{O1nom} = 2.0A$, $I_{O2, 3nom} = 0.17A$

Output

Chava	cteristics	Conditions		Output 1			Output 2			Output 3			Unit
Charac	ctensucs	Conditions		min	typ	max	min typ max min typ n		max	Unit			
V _{Oi}	Output voltage initial setting and accuracy	$T_C = +25^{\circ}C, I_O = I_{O}$	nom, V _I = 26 V	5.03	5.06	5.10	14.80	15.00	15.20	-14.80	-15.00	-15.20	V
V _O	Output voltage tolerance band	I _O =0.1 1.0 × I _O and long term drift		4.90		5.25	14.40		15.60	14.40		15.60	V
	Idling voltage	I _O = 0 A				5.25		18.00	19.80		18.00	19.80	٧
	Line regulation	I _O =I _O nom				81			330			330	mV
	Load regulation	$I_{O1}=0.1 1.0 \times I_{O}$ $V_{I}=26 \text{ V}$	nom, I _{O2, 3} = I _{Onom} ,			182							mV
t _{tr}	Load transient recovery time	I _O =0.1 1.0 × I _O nom, V _I = 26 V load step = 80% of I _O nom			100			250			250		μS
V _{tr}		di			+250			+750			+750		mV
Vtr	Load transient voltage	dt			-250			-750			-750		mV
	Short term drift	t = 010 minutes			-15			-45			-45		mV
T _{coeff}	Temperature coefficient	Io=Ionom, To < To m	I _O =I _O nom, T _C < T _C max		-0.5			-1.5			-1.5		mV/°C
t _r	Ramp-up time	I _O =	$0.1\dots\ 0.9\times V_O$		20			20			20		ms
t _s	Start-up time	$ \begin{array}{c} 0.1 & 1.0 \times I_{O} \text{ nom,} \\ V_{I} = 26 \text{ V} \end{array} $	From V_l connection to $V_O = 0.9 \times V_{Oi}$		30			30			30		ms
Ю	Output current			0		3.0	0		0.5	0		0.5	Α
P _O max	Max total output power	*			min 15								W
l _{lim}	Current limiting threshold	T _C < T _C max	T _C < T _C max				min 1.02 × P _O max**						
I _{sc}	Short curcuit current	V _O =0.2 0.5 V, T _A =25°C Hick-up			<0.5			<0.5			<0.5		Α
			20 Hz 5 MHz			100			110			100	mV _{p-p}
V _O ac	Output ripple & noice	I _O =I _O nom	DC 50 MHz			130			150			150	mV _{p-p}
			1 MHz bandwidth			40			40			40	mV_{rms}
SVR	Supply voltage rejection (ac)	f = 100 Hz sine way (SVR = 20 log (1 V _p		50			40			40			dB

 $^{^{\}star}$ See also Power derating p. 13. Max output power on output 2 and 3 jointly is min 10 W

Characte	eristics	Conditions	min	typ	max	Unit
η	Efficiency	I _O =I _{Onom} , V _I = 26 V	80	82		%
P _d	Power dissipation	I _O =I _O nom		3.3		W

 $^{^{**}}$ I_{lim} on each output is set by the total load

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 $T_C = 0...+95$ °C, $V_I = 18...36$ V unless otherwise specified. $I_{O1nom} = 2.0$ A, $I_{O2nom} = 0.2$ A, $I_{O3nom} = 0.5$ A

Output

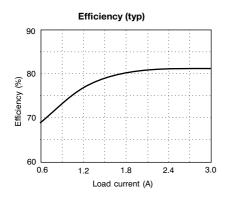
01		Conditions		Output 1		Output 2			Output 3			Unit	
Cnara	cteristics	Conditions		min	typ	max	min typ max m		min	typ	max	Unit	
V _{Oi}	Output voltage initial setting and accuracy	$T_C = +25$ °C, $I_O = I_O$	nom, V _I = 26 V	5.03	5.06	5.10	11.90	12.10	12.30	-4.99	-5.06	-5.14	V
V _O	Output voltage tolerance band	I_O =0.1 1.0 × I_{OI} and long term drift		4.90		5.25	11.52		12.36	4.75		5.25	V
	Idling voltage	I _O = 0 A				5.25		15.00	16.00		6.00	6.50	V
	Line regulation	I _O =I _O nom				90			336			110	mV
	Load regulation	$I_{O1}=0.1 1.0 \times I_{O}$ $V_{I}=26 \text{ V}$	nom, I _{O2, 3} = I _O nom,			190							mV
t _{tr}	Load transient recovery time	I _O =0.1 1.0 × I _O nom, V _I = 26 V load step = 80% of I _O nom			100			200			100		μS
.,		$\frac{di}{dt}$ <1A/µs			+250			+600			+250		mV
V _{tr}	Load transient voltage	dt < τΑνμ\$			-250			-600			-250		mV
	Short term drift	t = 010 minutes			-15								mV
T _{coeff}	Temperature coefficient	Io=Ionom, To < To m	Io=Ionom, Tc < Tc max		-0.5			-1.0			-0.5		mV/°C
t _r	Ramp-up time	I _O =	0.1 0.9 × V _O		20			20			20		ms
ts	Start-up time	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	From V_l connection to $V_O = 0.9 \times V_{Oi}$		30			30			30		ms
lo	Output current			0		3.0	0		0.6	0		1.0	Α
Pomax	Max total output power	*					min 15						W
I _{lim}	Current limiting threshold	T _C < T _C max					min $1.02 \times P_0 \text{ max}^{**}$						
I _{sc}	Short curcuit current	V _O = 0.2 0.5 V, T _A = 25 °C Hick-up			<0.5			<0.5			<0.5		Α
			20 Hz 5 MHz			100			110			100	mV _{p-p}
V _O ac	Output ripple & noice	I _O =I _O nom	DC 50 MHz			130			150			120	mV _{p-p}
			1 MHz bandwidth			40			40			35	mV _{rms}
SVR	Supply voltage rejection (ac)	f = 100 Hz sine way (SVR = 20 log (1 Vp	ve, 1 V _{p-p} , V _I = 26 V -p/V _{Op-p}))	50			43			50			dB

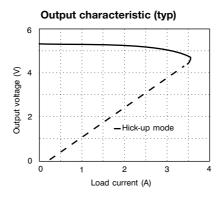
^{*} See also Power derating p. 13. Max output power on output 2 and 3 jointly is min 10 W

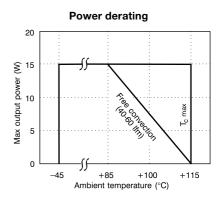
Characte	eristics	Conditions	min	typ	max	Unit
η	Efficiency	I _O =I _{Onom} , V _I = 26 V	79.5	81		%
P _d	Power dissipation	I _O =I _O nom		3.5		W

^{**} I_{lim} on each output is set by the total load

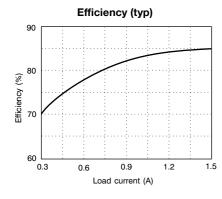
PKC 2111 PI

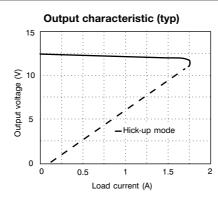


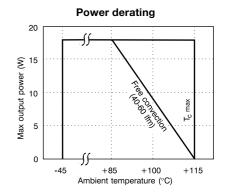




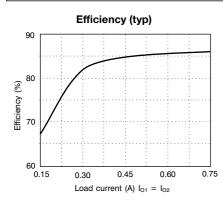
PKC 2113 PI

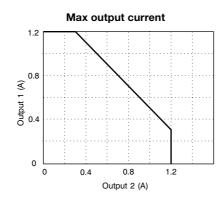


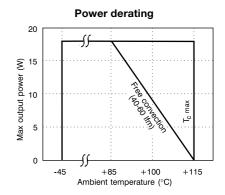




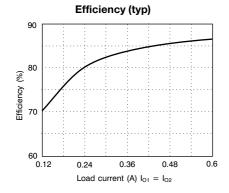
PKC 2121 PI

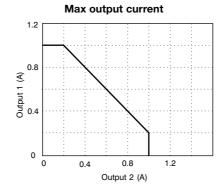


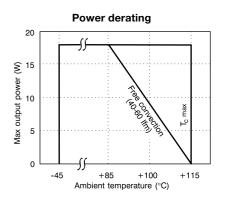




PKC 2126 PI

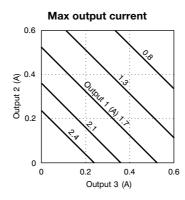


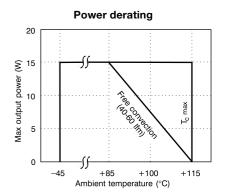




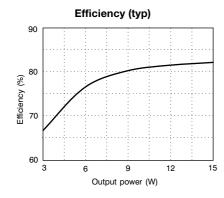
PKC 2131 PI

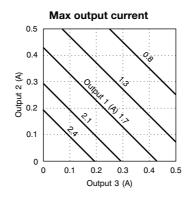
80 80 80 60 9 12 15 Output power (W)

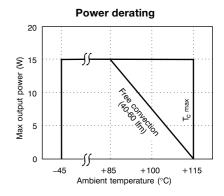




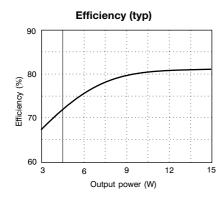
PKC 2132 PI

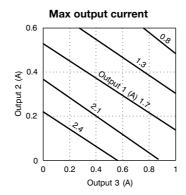


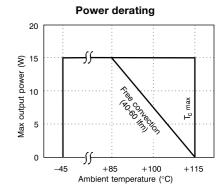




PKC 2135 PI



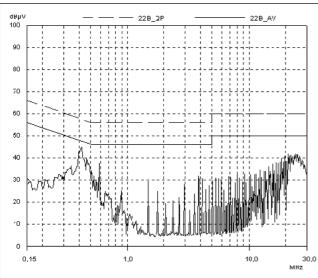




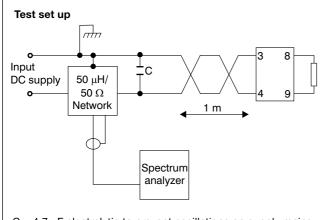
EMC Specifications

The PKC power module is mounted on a double sided printed circuit board (PB) with groundplane during EMC measurements. The fundamental switching frequency is 300 kHz \pm 15% @ I_{O} = $I_{O\ max}$ or $I_{O\ nom}$

Conducted EMI (input terminals)



PKC series typical conducted EMI performance



C = 4.7 μF electrolytic to prevent oscillations on supply mains

The PKC meets class A in VDE 0871/0878, FCC Part 15J, and CISPR 22 (EN 55022).

Radiated EMI

To minimize radiation it is recommended to have a ground or earth plane in the printed board (PB).

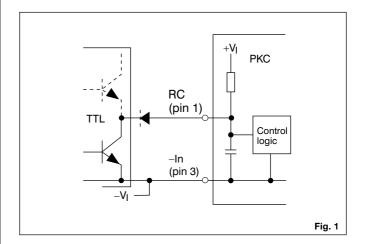
Output Ripple & Noise (Voac)

Output ripple & noise is measured at the output terminals with a 50 MHz oscilloscope and a true rms DVM (crest factor >4.5). The oscilloscope's input impedance should be adapted to the impedance of the coax cable and the output terminal connection should have a minimum ground wire loop.

Operating information

Remote Control (RC)

Turn-on or turn-off can be realized by using the RC-pin. Normal operation is achieved if pin 1 is open (NC). If pin 1 is connected to pin 3 the PKC DC/DC power module turns off. To ensure safe turn-off the voltage difference between pin 1 and 3 shall be less than 1.8 V. RC is TTL open collector compatible (see fig. 1). Pin 1 is an output and no current should be driven into pin 1. Use a diode if necessary e.g. totem pole TTL logic. The internal pull-up resistance is 15 kW.

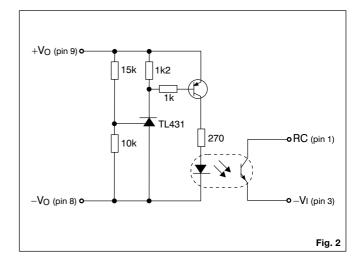


Input and Output Impedance

Both the source impedance of the power feeding and the load impedance will interact with the impedance of the DC/DC power module.

It is most important to have the ratio between L and C as low as possible, i.e. a low characteristic impedance, both at the input and output, as the power modules have a low energy storage capability.

A capacitive compensation is necessary if the source or load inductance is larger than 10 μ H. Use wet electrolytic capacitors. Their equivalent series resistance together with the capacitance acts as a lossless damping filter. Suitable capacitor values are in the range10–100 μ F.



Turn-off Input Voltage (V_{loff})

The input voltage is monitored and the PKC DC/DC power module will turn on and turn off at predetermined levels. The levels can be decreased by means of an external resistor connected between pin 1 and pin 5.

A 80 k Ω resistor will decrease the shutdown voltage below 17 V. To maintain the nominal output voltage at input voltages below V_I min it may be necessary to decrease the load.

Maximum Capacitive Load

The maximum recommended capacitance connected direct t the PKC DC/DC power modules output without resistance or inductance in series is 100 $\mu\text{F/A}$ (output current rating). Connect capacitors across the load for maximum effectiveness and maximum stability margins.

Over Voltage Protection (OVP)

The remote control can be utilized also for OVP by using the external circuitry in fig. 2. Resistor values are for 5 V output applications, but can easily be adjusted for other output voltages and the desired OVP level.

Current Limiting Protection

The output power is limited at loads above the output current limiting threshold ($I_{\rm lim}$), specified as a minimum value. As the PKC multiple output models are power limited, current limiting threshold for an individual output is set by the loads on the other outputs. The power module can withstand continuous short circuit without destruction. A hick-up mode is used on all models to minimize the internal power dissipation. The hick-up time constant is set by the slow start.

Quality

Reliability

Meantime between failure (MTBF) is calculated and verified by field data statistics to >2 million hours at full output power and a case temperature of 75°C, using the Ericsson failure rate data system. For more information see Design Note 002.

Quality Statement

The products are designed and manufactured in an industrial environment where quality systems and methods like ISO 9000, 6σ and SPC, are intensively in use to boost the continuous improvements strategy. Infant mortality or early failures in the products are screened out by a burn-in procedure and an ATE-based final test.

Conservative design rules, design reviews and product qualifications, plus the high competence of an engaged work force, contribute to the high quality of our products.

Warranty

Ericsson Microelectronics warrants to the original purchaser or end user that the products conform to this Data Sheet and are free from material and workmanship defects for a period of five (5) years from the date of manufacture, if the product is used within specified conditions and not opened. In case the product is discontinued, claims will be accepted up to three (3) years from the date of the discontinuation.

For additional details on this limited warranty we refer to Ericsson Microelectronics AB's "General Terms and Conditions of Sales", or individual contract documents.

Limitation of liability

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Product Program

V		V _O /I _O max	P _O max	Ordering No.		
Vı	Output 1	Output 2	Output 3	FO IIIAX	Ordering No.	
24 V	5 V/3 A 12 V/1.5 A +12 V/1.2 A +15 V/1 A +5 V/3 A +5 V/3 A	-12 V/1.2 A -15 V/1 A +12 V/0.6 A +15 V/0.5 A	-12 V/0.6 A -15 V/0.5 A	15 W 18 W 18 W 18 W 15 W	PKC 2111 PI PKC 2113 PI PKC 2121 PI PKC 2126 PI PKC 2131 PI PKC 2132 PI	

Ericsson Microelectronics AB SE-164 81 KISTA, Sweden Phone: +46 8 757 5000 www.ericsson.com/microelectronics

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The latest and most complete information can be found on our website!

Data Shee